Silicon P-Channel MOS FET

HITACHI

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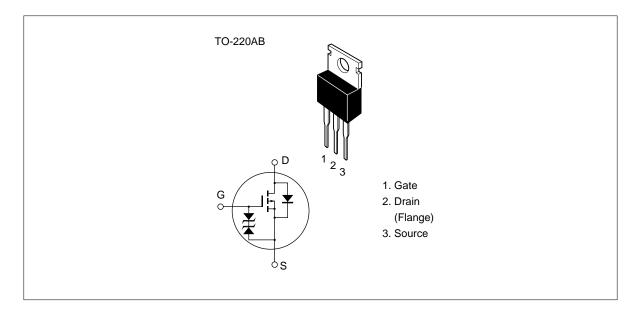
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
 - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

Outline



Absolute Maximum Ratings (Ta = 25°C)

Symbol	Ratings	Unit V	
V _{DSS}	-60		
V _{GSS}	±20	V	
I _D	-10	A	
I *1 D(pulse)	-40	A	
I _{DR}	-10	A	
Pch*2	40	W	
Tch	150	°C	
Tstg	-55 to +150	°C	
	V_{DSS} V_{GSS} I_D $I_{D(pulse)}^{*1}$ I_{DR} Pch^{*2} Tch	V -60 V ± 20 I -10 I -40 I -10 Pch*2 40 Tch 150	

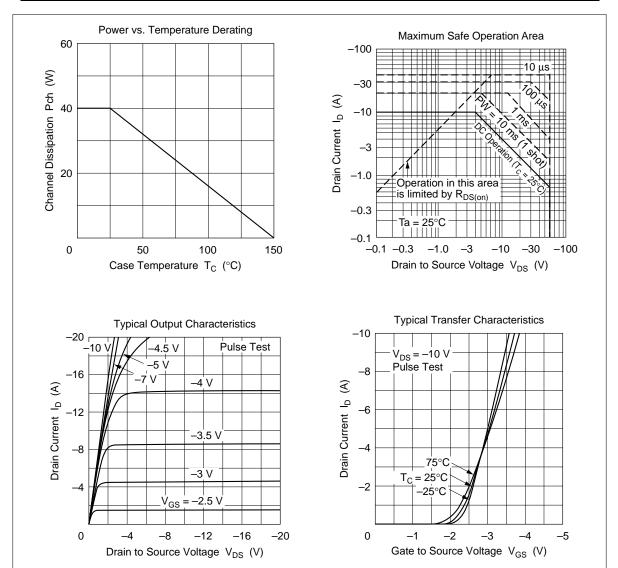
Notes 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

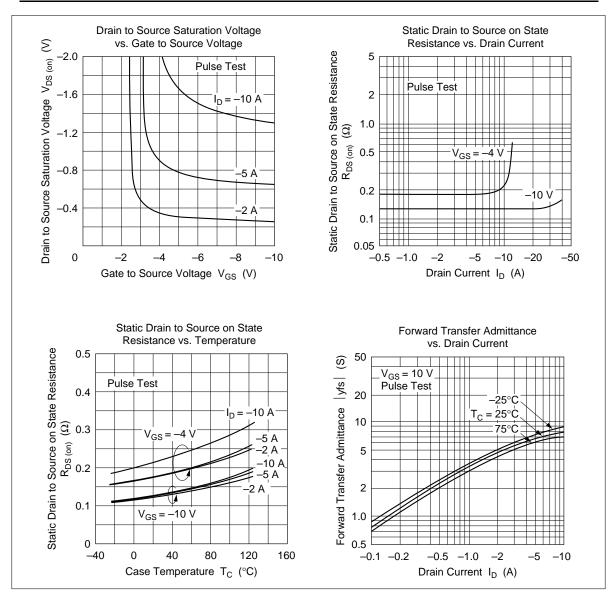
2. Value at T_c = 25° C

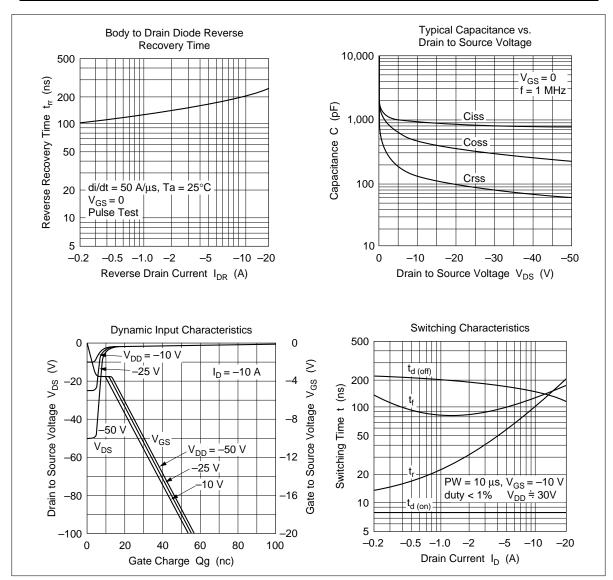
Electrical Characteristics (Ta = 25°C)

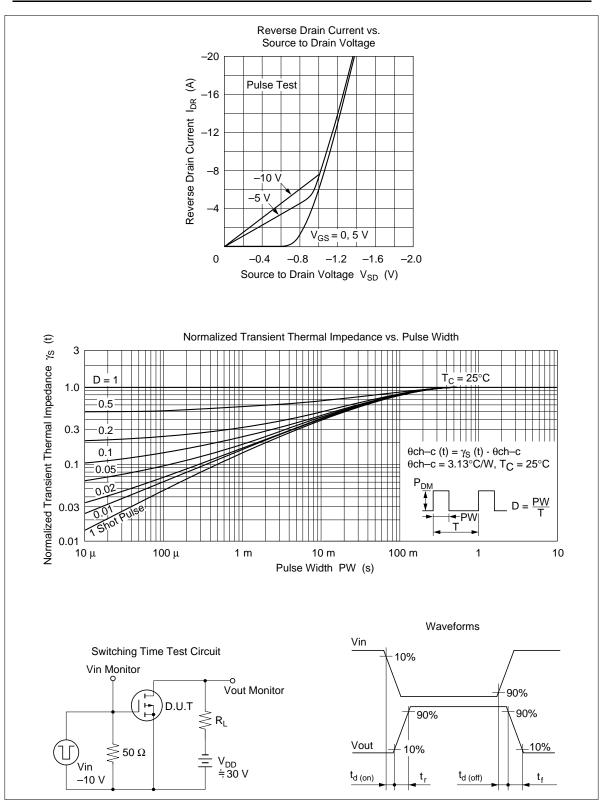
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	-60	_	_	V	$I_{\rm D} = -10$ mA, $V_{\rm GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{g} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_		±10	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}		_	250	μA	$V_{\rm DS} = -50$ V, $V_{\rm GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	-1.0		-2.0	V	$I_{\rm D} = -1 \text{ mA}, V_{\rm DS} = -10 \text{ V}$
Static drain to source on state	R _{DS(on)}	_	0.13	0.18	Ω	$I_{\rm D} = -5$ A, $V_{\rm GS} = -10$ V ^{*1}
resistance		_	0.18	0.25		$I_{\rm D} = -5$ A, $V_{\rm GS} = -4$ V ^{*1}
Forward transfer admittance	y _{fs}	4.0	6.5		S	$I_{\rm D} = -5$ A, $V_{\rm DS} = -10$ V ^{*1}
Input capacitance	Ciss	_	900	_	pF	$V_{\rm DS} = -10 \ V, \ V_{\rm GS} = 0,$
Output capacitance	Coss		460		pF	f = 1 MHz
Reverse transfer capacitance	Crss		130		pF	
Turn-on delay time	t _{d(on)}		8		ns	$I_{\rm D} = -5 \text{ A}, V_{\rm GS} = -10 \text{ V},$
Rise time	t,		65		ns	$R_{L} = 6 \Omega$
Turn-off delay time	t _{d(off)}		170		ns	
Fall time	t _f		105	_	ns	
Body to drain diode forward voltage	V_{DF}		-1.1		V	$I_{\rm F} = -10$ A, $V_{\rm GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	—	200		ns	$I_{F} = -10 \text{ A}, V_{GS} = 0,$ $di_{F}/dt = 50 \text{ A}/\mu\text{s}$

Note 1. Pulse test









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